

11/1/2022

BEEE Assignment -1

Q.1.

(1) Transistor is used as an amplifier in active mode.

Q.2.

(2) "If the external reverse bias voltage is increased to a value called the Breakdown voltage Reverse current will decrease."

is False.

Reverse current should drastically Increase.

(3)

$$V_{CC} = 15 \text{ V}$$

$$R_1 = 4.7 \text{ k}\Omega \quad R_2 = 1.5 \text{ k}\Omega$$

Base Voltage will be,

$$\left(\frac{R_2}{R_1 + R_2} \right) V_{CC} = \left(\frac{1.5}{1.5 + 4.7} \right) 15 = 3.629 \text{ V}$$

Q.3.

(4) In a PNP BJT, Emitter is heavily doped and Base is lightly doped.

(5) Cut off region

(6.) $I_E = I_C + I_B$

largest current flows in the emitter

(7) B. "Zener diodes are used in forward Biased condition for voltage regulators"

is false. They are used in reverse

Poss-

(8) $I_E = 4.2 \text{ mA}$

$$I_C = 4.0 \text{ mA}$$

For CB config,

$$\times_{DC} = \frac{I_C}{I_E} = \frac{4}{4.2} = 0.9523$$

(D) option

(9) D. "The emitted light tends to be monochromatic and that depends on the band gap and impurities added during the LED construction. A small exposed area on one layer of the semiconducting material permits photons to be emitted as visible light in an LED."

(10) hie stands for input impedance in CE arrangement with output shorted.

Q. (2) Voltage $V(t) = 300 \cos 100(\omega t)$
 is applied to half wave Rectified.
 with $R_L = 5 \text{ k}\Omega$. Diodes are ideal.
 is series with source resistance $R_S = 54 \text{ k}\Omega$
 Find all parameters.

Ans

$$V_t = 300 \cos(100\omega t) \text{ V}$$

$$R_L = 5 \text{ k}\Omega$$

$$R_S = \underline{54} \text{ k}\Omega \quad (\text{Rou NO : } 54)$$

$$\text{Here, } V_t = 300 \cos 100\omega t$$

$$V_{\max} = 300 = V_{\text{peak}}$$

As diode is ideal. R_D is ignored.

$$\begin{aligned} R_{\text{total}} &= R_L + R_S \\ &= 54 + 5 = 59 \text{ k}\Omega \end{aligned}$$

$$\text{So } I_{\max} = \frac{300}{59} \times 10^{-3} \text{ A.}$$

$$= 5.08 \times 10^{-3} \text{ A}$$

$$= \underline{\cancel{5.08}} \frac{5.08}{\cancel{1}} \text{ mA}$$

$$I_{\text{RMS DC}} = \frac{5.08}{\pi} = \frac{I_m}{\pi} = \underline{1.61} \text{ mA}$$

$$I_{\text{avg}} = \frac{I_m}{2} = \underline{2.54} \text{ mA}$$

Power in load due to DC component
 of current = $P_{DC} = I_{DC}^2 \times R_L$
 $= 1.61^2 \times 5 \text{ k}\Omega$
 $= 12.9 \text{ W} \times 10^{-3}$

Power is dissipated due to AC current,

$$P_{AC} = I_{rms}^2 \times (R_L + R_S)$$
 $= 2.54^2 \times (59000) \times 10^{-6}$
 $= 380.64 \text{ W} \times 10^{-3}$

Efficiency of Rectifier = $\eta = \frac{P_{DC}}{P_{AC}}$

$$\eta = \frac{12.9 \times 10^{-3}}{380.64 \times 10^{-3}} = \underline{\underline{3.39\%}}$$

Ripple factor :

$$\begin{aligned} r &= \sqrt{\left(\left(\frac{I_{rms}}{I_{DC}}\right)^2 - 1\right)} \\ &= \sqrt{\left(\frac{2.54}{1.61}\right)^2 - 1} \\ &= \underline{\underline{1.22}} \end{aligned}$$

Load current (I_m) = $I_{DC} = 1.61 \text{ mA}$

DC Power

$P_{DC} = 12.9 \text{ mW}$

AC Power

$P_{AC} = 380.64 \text{ mW}$

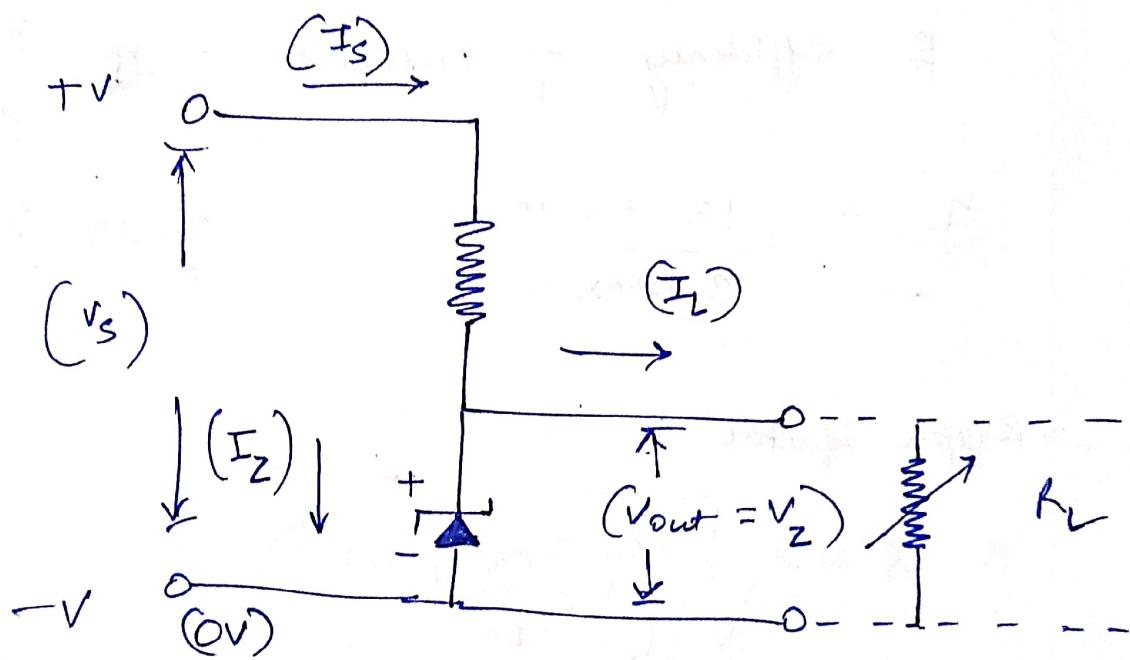
Rectifier efficiency

$\eta = 3.39\%$

Ripple factor

$r = 1.22$

- Q(3). Using Zener Regulation circuit shown below, calculate
1. Max current through diode.
 2. The value of the series resistor R_s with no load.
 3. Load current I_L if a load resistor $\cancel{R_L} + 1\text{ k}\Omega$ is connected across Zener diode
 4. Zener current I_Z at full load.



$$5 + 4 = 9 \text{ V}$$

$$\therefore V_z = \cancel{54 \text{ V}} \quad [\text{Roll No. 54}]$$

$$V_s = 2 \cdot (V_z) + 2 = \cancel{110 \text{ V}} \quad [18 + 2 = 20 \text{ V}]$$

$$P_{Z_{\max}} = 9 \text{ fWB} \quad [\text{Div} < 10]$$

$$= \cancel{9 \text{ fWB}} \quad [P = \text{Div} \cancel{\text{fWB}}]$$

$$\underline{9 \text{ W}}$$

① Maximum current through Zener diode

$$I_{Z_{\max}} = \frac{P_{\max}}{\text{Voltage}} = \frac{9}{9} = \underline{\underline{1 \text{ A}}}$$

② Value of R_S with No load

$$R_S = \frac{V_S - V_Z}{I_{Z_{\max}}} = \frac{20 - 9}{1} = \underline{\underline{11 \text{ m}\Omega}}$$

③ Load current if I_L is $1 \text{ k}\Omega$.

$$I_L = \frac{V_Z}{R_L} = \frac{9}{1000} = \underline{\underline{9 \text{ mA}}}$$

④ I_Z at full load

$$\begin{aligned} I_Z &= I_S - I_L \\ &= 1000 \text{ mA} - 9 \text{ mA} \\ &= \underline{\underline{991 \text{ mA}}} \end{aligned}$$

Q. 4. CE config Voltage divider Bias Circuit is shown

$$V_{CC} = 15 \text{ V}$$

$$R_1 = 54 \text{ k}\Omega$$

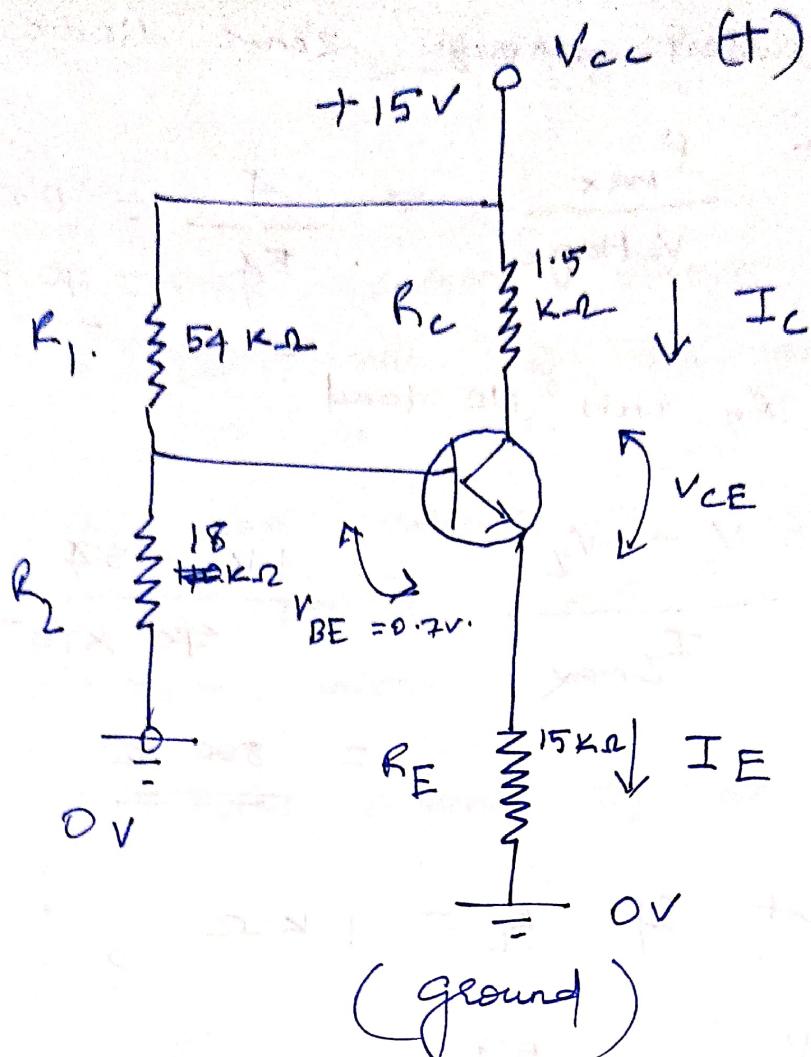
$$R_L = 9 \times 2 = 18 \text{ k}\Omega$$

$$R_C = 1.5 \text{ k}\Omega$$

$$R_E = 15 \text{ k}\Omega$$

$$\beta = 160$$

Find Q point.



$$\begin{aligned}
 V_{BB} &= V_{CC} \left(\frac{R_2}{R_1 + R_2} \right) = 15 \left(\frac{\cancel{18}}{\cancel{18} + 54} \right) \\
 &= 15 \left(\frac{18}{18 + 54} \right) = \underline{\underline{10.05V}} \quad \underline{\underline{0.25V}} \\
 &= \underline{\underline{3.75V}}
 \end{aligned}$$

$$\begin{aligned}
 V_E &= V_{BB} - 0.7 = 3.75 - 0.7 \text{ V} \\
 &= \underline{\underline{3.05V}}
 \end{aligned}$$

$$Z_{eq} \neq \frac{r_B}{R_E} \quad \text{so} \quad I_E = \frac{V_E}{R_E} = \frac{3.05}{15000} = \underline{\underline{0.20mA}}$$

$$\text{But } I_C \propto I_E = \underline{\underline{0.20mA}} = I_{CQ}$$

$$\begin{aligned}
 V_{CE} &= V_{CC} - I_C R_C = 15 - (0.20)(1.5 \times 10^3) \times 10^{-3} \\
 &= 15 - 0.3 = \underline{\underline{14.7V}}
 \end{aligned}$$

$$V_{CE} = V_C - V_E$$

$$= 14.7 \text{ V} - 3.05 \text{ V}$$

$$= \cancel{11.65} \text{ V}$$

$$\text{So Q point} = (I_C, V_{CE})$$

$$= (0.20 \text{ mA}, \underline{\underline{11.65 \text{ V}}})$$